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Backside fluorine-functionalized graphene layer for ammonia detection

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Graphene is a remarkable material with the best surface to volume ratio as a fact of its 2D nature, which implies that every atom can be considered as a surface one. These features make graphene attractive for use as a sensing material, however, the limiting factor is the chemical inertness of pristine graphene. Here we propose a way to create reactive centers by removal of fluorine atoms from the outer surface of fluorinated graphene while preserving the backside fluorination. Such partially recovered graphene layers were produced by acting of hydrazine-hydrate vapor on initially non-conducting fluorinated graphite. Reduction degree of the material and its electrical response revealed on ammonia exposure were controlled by measuring the surface conductivity. We showed experimentally that the sensing properties depend on the reduction degree and found the correlation of the adsorption energy of ammonia with the number of residual fluorine atoms by the use of quantum-chemical calculations.

1. Introduction

Graphene is a two-dimensional form of graphite considered as a single layer of the material. Its unique electronic properties, supported by numerous physical measurements, has been of a great interest in both fundamental and practical aspects.\textsuperscript{1} Right after publishing the first studies on graphene demonstrating the change in the electronic state under the influence of an electric field,\textsuperscript{2} the idea of its use as a molecular sensor attracted much attention of sensor researchers.\textsuperscript{3} It was shown that interaction of a graphene surface with molecules in a gas phase produces a change in the surface electronic state.\textsuperscript{4-6} Moreover, the surface conductivity change can be induced by an electric field or charge transfer from/to an adsorbed molecule. These graphene properties allow using the material as a molecular sensor.\textsuperscript{7} The sensing properties of graphene structures obtained by mechanical cleavage,\textsuperscript{8} CVD synthesis,\textsuperscript{9-12} and chemical exfoliation\textsuperscript{15-21} have been investigated over past few years. However, it was figure out that pristine graphene is not a good sensing material because of the chemical inertness of its surface. In addition, it is not possible to produce graphene samples of more than several tens of microns in a plane dimension using the traditional exfoliation method, which limits the overall sensitivity. Graphene synthesized by CVD method shows good results on the sensing properties,\textsuperscript{11} which is probably due to a higher defect level of CVD graphene in comparison with exfoliated one. In general, the graphene properties depend on the degree of its chemical modification. It was also shown that the deposition of semiconductor nanoparticles on a graphene surface could create selective gas sensors.\textsuperscript{13} Theoretical studies confirm that the presence of defects in a graphene lattice, for example, replacement of carbon atoms with silicon ones enhances the sensing properties of the material.\textsuperscript{5,14}

The greatest number of research activities has been conducted on the study of sensors based on graphite oxide. Recovered from graphene oxide layers exhibit sensing properties to exposure to nitrogen dioxide,\textsuperscript{15-18,19} ammonia,\textsuperscript{18} explosives,\textsuperscript{19, 20} and vapor of organic solvents.\textsuperscript{21} This type of the structure should be considered as the most effective for such application as a manufacture of printed sensor samples. However, graphite oxide, particularly in the form of films made of separate overlapping particles with the size of about 10 µm, may not be the best sensor contender. It is known that oxygen atoms are arranged irregularly on the graphene planes forming different types of chemical bonds with the oxygen functional groups such as epoxy, hydroxyl, and carboxyl.\textsuperscript{22}

Fluorinated graphite can be considered as an alternative to graphite oxide. Fluorination at room temperature results in fluorine bonding with approximately a half the carbon atoms, the bare atoms form the chains of conjugated carbon-carbon bonds.\textsuperscript{23} Previously, we proposed designing a graphene layer on the surface of fluorinated graphite C\textsubscript{F} by water\textsuperscript{24} or hydrazine\textsuperscript{25} vapor exposure and revealed an increase of the layer resistance upon ammonia adsorption. We expect that in such a reaction chemical bonds C–F remain on the inner side of the graphene. Electrical and sensing properties of such a one-side fluorinated graphene sheet will differ significantly from that of graphene. Being electrically conductive, the graphene sheet will have a significant positive charge due to the transfer of electron density to attached fluorine atoms.
Here we demonstrate that the sensor properties of such a layer can be controlled by reduction time and invoke calculations within density functional theory (DFT) for understanding the nature of reduced graphene – ammonia interaction. The hydrazine-hydrate was used as a reductant, and changes in the structure and chemical composition of the surface layers of fluorinated graphite were monitored using the methods of Raman scattering and X-ray photoelectron spectroscopy (XPS).

2. Experimental

2.1. Materials and characterization

A plate of highly ordered pyrolytic graphite (HOPG) was fluorinated using saturated vapors of BrF$_3$ and Br$_2$ during 30 days. As the result of covalent attachment of fluorine atoms to both sides of a graphene sheet, the plate thickness increased by two times at least. For sensor preparation, the plate was split in flakes with a typical size about 2.5×5 mm$^2$. Optical microscopy analysis showed that the detached flakes have multilayered structure and uniform bronze coloring (Figure 1). A large number of wrinkles seen in the image indicates disturbance of initially planar graphene sheets with the fluorination.

![Figure 1. Experimental setup for the electrical measurements. An optical image of a fluorinated graphite C$_2$F$_x$ sample (x < 1) with applied silver contacts is shown in the center.](image)

A flake of fluorinated graphite (FG) was fixed on a teflon plate, and two gold wire contacts were attached to the flake surface by a silver glue, which formed two silver terminals with a distance of about 0.5 mm between them. A glass cell with a volume of 25 mL was used for the chemical reduction of the sample surface and for the sensor measurements as well. Argon with a flow rate of 10 mL/min was bubbled through a barbater with hydrazine-hydrate and directed into the glass cell. A conductive layer on the flake surface was produced by the following reaction:

$$C_2F_x + N_2H_4 \rightarrow C + HF + N_2$$  \hspace{1cm} (1)

The measurements of sample conducting properties were carried out with a picoammeter KEITHLEY 6485. The change in resistance was observed by applying a DC voltage bias of 1V to the sample contacts and registering the current flowing through the sensor. The schematic view of the experimental setup is shown in Figure 1. By varying the recovery time, we obtained samples with different reduction degree, which was controlled by measuring the sample conductivity. Depending on the treatment time (30, 45, 60, and 120 min), the samples were denoted as FG30, FG45, FG60, and FG120, respectively. A conductivity of the top layer was described by at least three exponential functions, indicating a rapid process of fluorine removal from the surface and diffusion of reducing compound to the deeper layers of fluorinated graphite.

The change in the structure and surface composition of the samples after exposure to NH$_3$ was examined using Raman scattering and XPS. The Raman spectra were obtained on a Triplemate SPEX spectrometer using a 488 nm excitation. The XPS spectra were recorded on a Phoibos 150 Spec spectrometer using a monochromatized Al Kα radiation (E$_{\text{Kα}}$ = 1486.6 eV). A pass energy of the electron energy analyzer was set at 20 eV. The angle between the excitation beam and the entrance of the electron detector was 55°. The analyzed area was about 1 mm×2 mm. Because of dielectric properties of the initial sample, a charging effect was observed during the measurements, which was compensated by low-energy electron irradiation. The binding energies were internally calibrated to the energy of 285 eV from surface carbon contaminations.

2.2. Gas sensing measurements

Sensing properties of reduced fluorinated graphite were characterized at ambient conditions (room temperature and atmospheric pressure) by exposing to ammonia vapor mixed with an inert gas (argon) using the test installation schematically shown in Figure 1. The measuring cell had two gas flow connectors (input and output). The gas flow rate in all experiments was 10 mL/min. Analyzed gas premixed with pure Ar making some concentration was released into the chamber. Gas flow rates were manipulated by mass flow controllers. A standard test cycle comprised three main steps, which included (1) exposing pure Ar to determine a baseline, (2) exposing the target gas mixed with Ar for response registration, and (3) regenerating the sensor to its original state using pure Ar (Figure S1). The relative response of the sensor was defined as the following:

$$\text{Response} = \frac{|R(T) - R(0)|}{R(0)} \hspace{1cm} (2)$$

2.3. Quantum chemical calculations

Theoretical modelling of ammonia molecules adsorption on the partially fluorinated graphene surface was carried out within DFT using the three-parametrical hybrid functional of Becke and Lee-Yang-Parr correlation functional with a pair correction accounting dispersion interactions (B3LYP-D3 method) as it is implemented in Jaguar 7.9 program package. Atomic orbitals were described by 6-31G* basis set, including polarization and diffuse functions for all atoms except hydrogen. Fluorinated graphene models were constructed based on C$_{73}$H$_{121}$ fragment, where hydrogen atoms saturate the dangling bonds of the boundary carbon atoms. The models of the following compositions C$_{73}$F$_{21}$, C$_{73}$F$_{5}$H$_{21}$, and C$_{73}$F$_{3}$H$_{21}$ were obtained by adding...
one, three, and five fluorine atoms, correspondingly, to the basal plane of the model fragment. Fluorine atoms were arranged at one side of the fragment in the assumption that incomplete reduction occurs on the internal side of the fluorinated graphite layer after treatment with hydrazine-hydrate. An ammonia molecule was oriented in such a way that the hydrogen atoms or nitrogen atom were directed to the central part of the non-fluorinated (external) model side. The geometry of the models was optimized completely by an analytical method to the gradient of $5 \times 10^{-4}$ atomic units for taking into account the shift of atomic position. The ultrafine grid was used for gradient calculations. Absence of imaginary frequencies indicated that the predicted configurations of ammonia correspond to the local minima in potential energy surfaces.

The adsorption energy of NH$_3$ on the reduced surface of fluorinated graphene was calculated as:

$$E_{ads} = E_{CF} + E_{NH_3} - E_{complex}$$  \hspace{1cm} (3)

where the first two terms in the right part of the equation correspond to the energy of optimized structures of the fluorinated graphene fragment and an ammonia molecule separately, and the last term is the total energy of the fragment with an adsorbate.

4. Result and discussion

The initial resistance of FG samples is several GΩ at room temperature. Exposing the samples to hydrazine vapor can remove fluorine atoms. That restores sp$^2$ carbon bonds making the sample surface conductive. The longer the reduction time the lower the resistance, which decreased by more than 3 orders of magnitude while reducing a fluorinated graphite flake for tens of minutes (Table 1).

<table>
<thead>
<tr>
<th>Sample</th>
<th>Reduction time (min)</th>
<th>Resistance (kΩ)</th>
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<tbody>
<tr>
<td>FG30</td>
<td>30</td>
<td>300</td>
</tr>
<tr>
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<td>60</td>
<td>30</td>
</tr>
<tr>
<td>FG120</td>
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Table 1. Resistance of fluorinated graphite samples FG30, FG45, FG60, and FG120 after reduction with different time treatment.

XPS C 1s spectra obtained at the excitation energy of 1486 eV, which allows X-rays to penetrate about three layers of fluorinated graphite, consist of two lines at 286 and 288.7 eV (Figure 2 (a)). The line at the higher binding energy comes from carbon atoms forming a C–F bond while carbon atoms unbonded to fluorine atoms contribute to the lower energy component. XPS data show an increase of the concentration of bare carbon atoms with the hydrazine-hydrate treatment, while the relative intensity of the C–F spectral component demonstrates an opposite behaviour. After the sample exposure for 120 min fluorine concentration reduces by half from 22 at. % in the initial sample to 12 at. % in the treated one. This fact indicates that after exposure to hydrazine-hydrate fluorine atoms leave the sample surface. The optimal exposure time is 30–45 min within our experimental conditions.

![Figure 2](image-url)
of functionalization and formation of conjugated chains. As discussed in that work, the band at 1425 cm\(^{-1}\) is related to distortions on the boundaries between flat carbon areas and fluorinated carbon regions in a layer. It can be seen the relative intensity ratio \(I_D/I_G\) decreases from 1 for the original FG sample to 0.5 for the samples exposed to hydrazine hydrate vapor. Besides, D’ peak drops with the exposure time increasing. That indicates an increase of crystallinity area in the graphene layer and decrease of imperfection related to the attachment of fluorine atoms. It is worth noting that after exposure time of 60 min the relative intensity of the W peak drops faster than D and D’ ones. This may stem from the fact that the hydrolysis process mentioned before forms defects in a graphite lattice that slows down the growth of the crystalline size despite the removal of fluorine atoms.

One of the evidences of fluorine atoms removal is the upraise of conductivity. However, the specific conductivity does not reach the typical values known for graphene (1 kΩ). Note, that fluorine atoms located on the surface are much easier accessible to the hydrazine reagent and reacted with a significantly higher probability compared to those inside the during reduction.

Figure 3 (a) shows the sensing properties of a reduced fluorinated graphite surface by demonstrating the change in the sensor resistance to the cyclic effect of 1 % NH\(_3\) with the corresponding partial pressure at room temperature. When the adsorption of NH\(_3\) on the surface occurs, the electron density transfers from a NH\(_3\) molecule to the fluorinated graphene layer. That reduces the concentration of the major charge carriers and increases the resistance. Figure 3(b) presents a single cycle of the sensor response when exposed to 1 % of NH\(_3\) for samples FG30, FG45, FG60, and FG120. The maximum relative response is 11 % for the sensor with 30 min reduction time. The relative response is dropped to 3 % for the sensor with 120 min reduction time. That happens due to removal of fluorine atoms from the internal surface of the first (the most active) layer of fluorinated graphite, which leads to a decrease in the number of reactive centers. Characteristic reaction times were calculated by fitting the experimental curves of adsorption and desorption with exponential functions and plotted against the recovery time (insert in Figure 3 (b)).

Both adsorption and desorption times increase with a reduction time increase. The response of the sensor to 1 % NH\(_3\) which was directly exposed to ammonia atmosphere (first cycle) and when it was exposed in flow using the gas system (second cycle) shown in Supplementary Information (Figure S2). For the first cycle, the characteristic absorption time is of ~50 sec and that for the second one is ~300 sec. In the latter case, the response time corresponds to the following two processes: establishing a constant concentration in the flask and adsorption of NH\(_3\) on the sample surface. The first characteristic time may be used to describe the sensor material itself, while the gas system setup is for the precise concentration control.

Experiments with different concentration of NH\(_3\) were performed for samples FG30 and FG60 (Figure 4). Sample FG30 with a reduction time of 30 min showed a response (resistance increase) of 10.2 % to 10000 ppm with the initial resistance of 300 kΩ. Sample FG60 with a reduction time of 60 min showed 5.3 % response to 10000 ppm with the initial resistance of 30 kΩ. A relative response value decreases from about 10 to 2 % with a NH\(_3\) concentration decrease from 10000 to 600 ppm for sample FG30 (Figure 4(a)). Sensor FG60 has a lower sensitivity in the concentration range from 10000 to 300 ppm with a drop in the relative response from 5 to 1 % (Figure 4 (b)).

Figure 3. (a) Reproducible change in resistance of sensor FG45 to the cycling effects of 1% NH\(_3\) at room temperature. Hatched bars correspond to the gas exposure. (b) One cycle of the sensor response showing the difference in amplitude and response time for samples FG30 - 1, FG45 - 2, FG60 -3, FG120 - 4. The inset shows response and recovery times versus reduction time.
Having a decreasing concentration and relative resistance as a function of ammonia pressure for (a) FG30 and (b) FG60. Dependence of the sensor response on NH₃ pressure is shown in the insets.

To describe the adsorption kinetics, we employ the Langmuir theory, which assumes that adsorption occurs at specific sites with a constant number, one site binds only one molecule, and the molecules do not interact with each other. To calculate the adsorption equilibrium constant $b$, we use the following equation:

$$\theta = \theta_\infty \frac{b \rho}{1 + b \rho}$$  \hspace{1cm} (4)

where $\theta_\infty$ is the total number of adsorption sites, $\theta$ is the number of occupied adsorption sites, and $\rho$ is the partial pressure of ammonia. On the other hand

$$\ln b = \Delta S \frac{R}{\Delta H_{ads}}$$  \hspace{1cm} (5)

where $\Delta H_{ads}$ and $\Delta S$ are the isosteric heat of adsorption equal to the absorption energy and entropy change. The latter member is estimated using equation.

$$\Delta S = \ln(RT)$$  \hspace{1cm} (6)

Fitting our experimental curves showing the relative resistance as a function of partial ammonia pressure (Figure 4 (a) and (b), insets) with the Langmuir isotherm, we get the adsorption constants $b$ equal to 0.0027 and 0.0022 for samples FG30 and FG60, correspondingly, in the assumption that the number of occupied adsorption sites $\theta$ is proportional to the resistance change. Then, with a help of Eq. 4, we calculate the ammonia adsorption energy for samples FG30 and FG60 that yields the values of 0.227 and 0.233 eV. To compare the obtained values with the absorption energy of NH₃ on graphene, we used the experimental data for CVD-graphene (Figure 2(a) in Ref. 10) for plotting a dependence of the sensor response on the NH₃ pressure (Figure S3). The adsorption energy of NH₃ estimated from the dependence with the help of Eqs. (4)–(6) is 0.12±0.01 eV in consistence with the theoretical value of ~0.11 eV.\(^\text{16}\) Our sensor interacts with the adsorbate twice stronger, and we believe that the main reason is that fluorine atoms remain in the sample after the hydrazine hydrate treatment.

We further use these obtained energies to support the structure model, where the top (working) graphene surface is free of fluorines, while the backside has some fluorine atoms attached. For the C₇₃F₇₁ model with a single fluorine attached, we found the only stable ammonia molecule position when all three hydrogen atoms get as close as possible to carbon atoms surrounding the CF group (Figure 5 (a)). There are many possibilities for mutual distribution of several fluorine atoms on graphene. The simulation of X-ray emission and absorption spectra of fluorinated graphite C₇F obtained under the same conditions as the original samples used in this study revealed that fluorine atoms prefer to form chains on the basal plane sequentially linking with the opposite sides.\(^\text{27,34}\) Removal of fluorine atoms from one side leaves three backside fluorine atoms in the meta-position of two adjacent hexagons as it presented in the C₇₃F₂₁H₂₁ model. The relative arrangement of five fluorine atoms in the C₇₃F₂₁H₂₁ model was set to occupy the para- or meta- positions in relation to each other.

The geometry optimization of the C₇₃F₂₁H₂₁ and C₇₃F₁₊₁H₂₁ models with adsorbate found that ammonia tends to be located over the central CF group and there are two energetically favorable orientations. The calculated adsorption energies are listed in Table 2. In the former case a greater energy gain is achieved when ammonia “sits” on the top surface of fluorinated graphene by hydrogen atoms (Figure 5 (b)), while in the latter case the orientation by two “N–H” bonds is more preferable (Figure 5 (c)). The other found positions of ammonia relative to the surface of the C₇₃F₂₁H₂₁ and C₇₃F₁₊₁H₂₁ models are shown in Figure S4. The short distances between atoms in the ammonia and fluorinated graphene surface are collected in Table S1. The calculations show that the adsorption energy of NH₃ varies from 0.236 to 0.275 eV depending on the orientation of the molecule relative to the

**Figure 4.** Response of fluorinated graphene sensors towards NH₃ pulses with a decreasing concentration and relative resistance as a function of ammonia pressure for (a) FG30 and (b) FG60.
graphene surface and the backside fluorination degree. The values are slightly over the experimental energy, which is between 0.227 to 0.233 eV, as it determined for samples FG30 and FG60, respectively. The overestimation may arise from the chosen fluorination pattern as well as the theoretical approach. Moreover, the experimental sample can be considerably more complicated than the considered models. Actually, we cannot exclude penetration of NH$_3$ molecules between fluorinated layers when the sensor tested. Our calculations show that NH$_3$ readily interacts with fluorine via a hydrogen bonding similar to that predicted for graphene oxide. A fluorine atom is lifted over the graphene sheet and stabilizes at a distance of ~2.4 Å (Figure S5). The F–HNH$_2$ species form a charge-transfer complex with graphene, accepting about 0.93e. Since diffusion of the NH$_3$ molecules through the surface microcracks and sample sides should be restricted, we expect inducing a charge only on some areas of the graphene layer. Such positive charging could reduce the adsorption energy of NH$_3$ on the sensor surface in line with the experimental observation. The calculated binding energy of NH$_3$ in the complex is ~0.623 eV which is considerably larger than the values determined from the sensor measurements. The irreversible reaction of NH$_3$ molecules with fluorine in depth of the flake is likely responsible for a trend of conductivity increase observed with the sensor cycling (Figure 3 (a)).

The result of the calculation for the C$_{73}$F$_{12}$ model is presented in Figure 5 (d). The gradient isosurface is colored in accordance with the sign of the Laplacian and the strength of interaction. Large negative values (in red) correspond to strong attractions, and large positive values (in blue) indicate that the interactions are nonbonding. Areas of nonbonding overlapping are located at the center of each hexagonal ring, while a triangular-shaped surface between ammonia molecule and fluorographene is deeply red at the edges and weakly red-colored in the center. Thus, there is a slight attraction between the nitrogen atom and carbon one of the CF group despite the large distance between them, although, the greatest contribution to the adsorption energy comes from the attractions between hydrogen atoms and carbon atoms surrounding the CF group.

To reveal a character of noncovalent interactions between ammonia and backside fluorinated graphene we used an approach based on the electron density and its derivatives. The result of the calculation for the C$_{73}$F$_{12}$ model is shown in Figure 5 (d). The gradient isosurface is colored in accordance with the sign of the Laplacian and the strength of interaction. Large negative values (in red) correspond to strong attractions, and large positive values (in blue) indicate that the interactions are nonbonding. Areas of nonbonding overlapping are located at the center of each hexagonal ring, while a triangular-shaped surface between ammonia molecule and fluorographene is deeply red at the edges and weakly red-colored in the center. Thus, there is a slight attraction between the nitrogen atom and carbon one of the CF group despite the large distance between them, although, the greatest contribution to the adsorption energy comes from the attractions between hydrogen atoms and carbon atoms surrounding the CF group.

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<th>C$<em>{73}$F$</em>{12}$</th>
<th>C$<em>{73}$F$</em>{12}$</th>
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Table 2. Adsorption energy (eV) of ammonia on the surface of fluorinated graphene models calculated at B3LYP-D3/6-31G** level. H$_2$N and NH$_3$ correspond to initial orientations of the molecule relative to a reduce graphene layer.
Conclusions

Graphene layers were recovered by treating fluorinated HOPG with hydrazine hydrate vapor, and a residual fluorine content was controlled by reduction time as the Raman scattering and XPS spectroscopy indicated. Restoring sp² hybridization (π-type bonding) leads to a crucial enhance in the material electrical transport. On the one hand, the restored graphene layer keeps the major properties of pristine graphene because of the integrity of its hexagonal lattice, on the other hand, it has reactive centers making it not that inert to molecules in a gas phase. The flakes of the fluorinated HOPG with partially reduced surface were examined as a sensor to NH₃ exposure and both the response amplitude and response time were found to be dependent on the recovery degree of the sample. To make the sensor restored to its initial state, only air purging at room temperature required. The resistance as a function of NH₃ concentration (pressure) follows a general form of the Langmuir isotherm. Comparing the adsorption energy extracted from our experimental data with the quantum-chemical analysis, we conclude that the backside of graphene layer has some fluorine atoms attached chemically, which create reactive centers on the top of fluorine-free graphene surface. These centers attract the NH₃ molecules through noncovalent bonding, and interaction strength depends on the population density of fluorine atoms remaining on the backside of the graphene layer.

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Notes and references

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